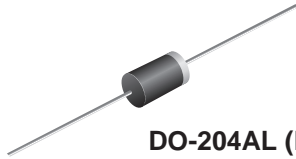


TRANSZORB® Transient Voltage Suppressors


DO-204AL (DO-41 Plastic)

Extended
Voltage Range

V_(BR) Unidirectional 6.8 to 540V
V_(BR) Bidirectional 6.8 to 440V
Peak Pulse Power 400W

Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Glass passivated junction
- 400W peak pulse power capability on 10/1000µs waveform, repetition rate (duty cycle): 0.01%
- Excellent clamping capability
- Low incremental surge resistance
- Very fast response time

Mechanical Data

Case: JEDEC DO-204AL molded plastic body over passivated junction

Terminals: Axial leads, solderable per MIL-STD-750, Method 2026

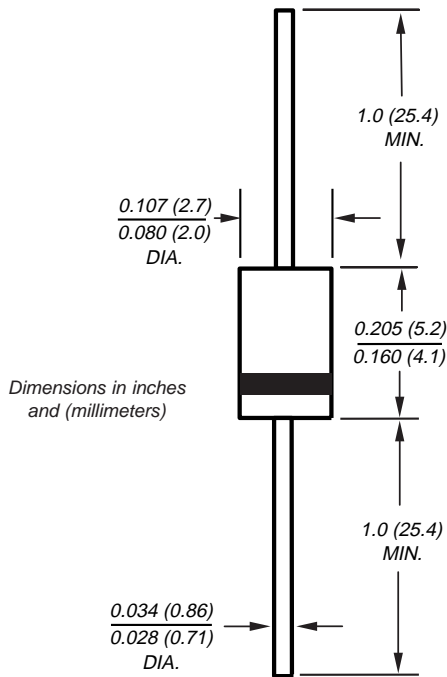
High temperature soldering guaranteed: 265°C/10 seconds, 0.375" (9.5mm) lead length, 5lbs. (2.3 kg) tension

Polarity: For unidirectional types the color band denotes the cathode, which is positive with respect to the anode under normal TVS operation

Mounting Position: Any **Weight:** 0.012 oz., 0.3 g

Packaging Codes – Options (Antistatic):

- 51 – 1K per Bulk box, 10K/carton
- 54 – 5.5K per 13" paper Reel (52mm horiz. tape), 16.5K/carton
- 73 – 3K per horiz. tape & Ammo box, 30K/carton



Devices for Bidirectional Applications

For bi-directional, use C or CA suffix for types P4KE6.8 thru types P4KE440 (e.g. P4KE6.8C, P4KE440CA). Electrical characteristics apply in both directions.

Maximum Ratings and Characteristics (T_A = 25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Peak power dissipation with a 10/1000µs waveform ⁽¹⁾ (Fig. 1)	PPPM	400	W
Peak pulse current with a 10/1000µs waveform ⁽¹⁾	IPPM	See Next Table	A
Steady state power dissipation at T _L = 75°C, lead lengths 0.375" (9.5mm) ⁽²⁾	P _{M(AV)}	1.0	W
Peak forward surge current, 8.3ms single half sine-wave unidirectional only ⁽³⁾	I _{FSM}	40	A
Maximum instantaneous forward voltage at 25A for unidirectional only ⁽⁴⁾	V _F	3.5/5.0	V
Typical thermal resistance junction-to-lead	R _{θJL}	60	°C/W
Typ. thermal resistance junction-to-ambient, L _{Lead} = 10mm	R _{θJA}	100	°C/W
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +175	°C

Notes: (1) Non-repetitive current pulse, per Fig.3 and derated above T_A = 25°C per Fig. 2

(2) Mounted on copper pad area of 1.6 x 1.6" (40 x 40mm) per Fig. 5

(3) Measured on 8.3ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum

(4) V_F = 3.5V for P4KE220(A) & below; V_F = 5.0V for P4KE250(A) & above

P4KE Series

Vishay Semiconductors
formerly General Semiconductor



Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Device Type	Breakdown Voltage $V_{(BR)}$ at $I_T^{(1)}$ (V)		Test Current I_T (mA)	Stand-off Voltage V_{WM} (V)	Maximum Reverse Leakage at V_{WM} $I_D^{(3)}$ (μ A)	Maximum Peak Pulse Current $I_{PPM}^{(2)}$ (A)	Maximum Clamping Voltage at I_{PPM} V_C (V)	Maximum Temperature Coefficient of $V_{(BR)}$ (% / °C)
	MIN	MAX						
P4KE6.8	6.12	7.48	10	5.50	1000	37.0	10.8	0.057
P4KE6.8A	6.45	7.14	10	5.80	1000	38.1	10.5	0.057
P4KE7.5	6.75	8.25	10	6.05	500	34.2	11.7	0.061
P4KE7.5A	7.13	7.88	10	6.40	500	35.4	11.3	0.061
P4KE8.2	7.38	9.02	10	6.63	200	32.0	12.5	0.065
P4KE8.2A	7.79	8.61	10	7.02	200	33.1	12.1	0.06
P4KE9.1	8.19	10.0	1.0	7.37	50	29.0	13.8	0.068
P4KE9.1A	8.65	9.55	1.0	7.78	50	29.9	13.4	0.068
P4KE10	9.00	11.0	1.0	8.10	10	26.7	15.0	0.073
P4KE10A	9.50	10.5	1.0	8.55	10	27.6	14.5	0.073
P4KE11	9.90	12.1	1.0	8.92	5.0	24.7	16.2	0.075
P4KE11A	10.5	11.6	1.0	9.40	5.0	25.6	15.6	0.075
P4KE12	10.8	13.2	1.0	9.72	1.0	23.1	17.3	0.076
P4KE12A	11.4	12.6	1.0	10.2	1.0	24.0	16.7	0.078
P4KE13	11.7	14.3	1.0	10.5	1.0	21.1	19.0	0.081
P4KE13A	12.4	13.7	1.0	11.1	1.0	22.0	18.2	0.081
P4KE15	13.5	16.5	1.0	12.1	1.0	18.2	22.0	0.084
P4KE15A	14.3	15.8	1.0	12.8	1.0	18.9	21.2	0.084
P4KE16	14.4	17.6	1.0	12.9	1.0	17.0	23.5	0.086
P4KE16A	15.2	16.8	1.0	13.6	1.0	17.8	22.5	0.086
P4KE18	16.2	19.8	1.0	14.5	1.0	15.1	26.5	0.088
P4KE18A	17.1	18.9	1.0	15.3	1.0	15.9	25.2	0.088
P4KE20	18.0	22.0	1.0	16.2	1.0	13.7	29.1	0.090
P4KE20A	19.0	21.0	1.0	17.1	1.0	14.4	27.7	0.090
P4KE22	19.8	24.2	1.0	17.8	1.0	12.5	31.9	0.092
P4KE22A	20.9	23.1	1.0	18.8	1.0	13.1	30.6	0.092
P4KE24	21.6	26.4	1.0	19.4	1.0	11.5	34.7	0.094
P4KE24A	22.8	25.2	1.0	20.5	1.0	12.0	33.2	0.094
P4KE27	24.3	29.7	1.0	21.8	1.0	10.2	39.1	0.096
P4KE27A	25.7	28.4	1.0	23.1	1.0	10.7	37.5	0.096
P4KE30	27.0	33.0	1.0	24.3	1.0	9.2	43.5	0.097
P4KE30A	28.5	31.5	1.0	25.6	1.0	9.7	41.4	0.097
P4KE33	29.7	36.3	1.0	26.8	1.0	8.4	47.7	0.098
P4KE33A	31.4	34.7	1.0	28.2	1.0	8.8	45.7	0.098
P4KE36	32.4	39.6	1.0	29.1	1.0	7.7	52.0	0.099
P4KE36A	34.2	37.8	1.0	30.8	1.0	8.0	49.9	0.099
P4KE39	35.1	42.9	1.0	31.6	1.0	7.1	56.4	0.100
P4KE39A	37.1	41.0	1.0	33.3	1.0	7.4	53.9	0.100
P4KE43	38.7	47.3	1.0	34.8	1.0	6.5	61.9	0.101
P4KE43A	40.9	45.2	1.0	36.8	1.0	6.7	59.3	0.101
P4KE47	42.3	51.7	1.0	38.1	1.0	5.9	67.8	0.101
P4KE47A	44.7	49.4	1.0	40.2	1.0	6.2	64.8	0.101
P4KE51	45.9	56.1	1.0	41.3	1.0	5.4	73.5	0.102
P4KE51A	48.5	53.6	1.0	43.6	1.0	5.7	70.1	0.102
P4KE56	50.4	61.6	1.0	45.4	1.0	5.0	80.5	0.103
P4KE56A	53.2	58.8	1.0	47.8	1.0	5.2	77.0	0.103
P4KE62	55.8	68.2	1.0	50.2	1.0	4.5	89.0	0.104
P4KE62A	58.9	65.1	1.0	53.0	1.0	4.7	85.0	0.104



Electrical Characteristics (Con't.) Ratings at 25°C ambient temperature unless otherwise specified.

Device Type	Breakdown Voltage $V_{(BR)}$ at $I_T^{(1)}$ (V)		Test Current I_T (mA)	Stand-off Voltage V_{WM} (V)	Maximum Reverse Leakage at V_{WM} $I_D^{(3)}$ (μ A)	Maximum Peak Pulse Current $I_{PPM}^{(2)}$ (A)	Maximum Clamping Voltage at I_{PPM} V_c (V)	Maximum Temperature Coefficient of $V_{(BR)}$ (% / °C)
	MIN	MAX						
P4KE68	61.2	74.8	1.0	55.1	1.0	4.1	98.0	0.104
P4KE68A	64.6	71.4	1.0	58.1	1.0	4.3	92.0	0.104
P4KE75	67.5	82.5	1.0	60.7	1.0	3.7	108	0.105
P4KE75A	71.3	78.8	1.0	64.1	1.0	3.9	103	0.105
P4KE82	73.8	90.2	1.0	66.4	1.0	3.4	118	0.105
P4KE82A	77.9	86.1	1.0	70.1	1.0	3.5	113	0.105
P4KE91	81.9	100	1.0	73.7	1.0	3.1	131	0.106
P4KE91A	86.5	95.5	1.0	77.8	1.0	3.2	125	0.106
P4KE100	90.0	110	1.0	81.0	1.0	2.8	144	0.106
P4KE100A	95.0	105	1.0	85.5	1.0	2.9	137	0.106
P4KE110	99.0	121	1.0	89.2	1.0	2.5	158	0.107
P4KE110A	105	116	1.0	94.0	1.0	2.6	152	0.107
P4KE120	108	132	1.0	97.2	1.0	2.3	173	0.107
P4KE120A	114	126	1.0	102	1.0	2.4	165	0.107
P4KE130	117	143	1.0	105	1.0	2.1	187	0.107
P4KE130A	124	137	1.0	111	1.0	2.2	179	0.107
P4KE150	135	165	1.0	121	1.0	1.9	215	0.108
P4KE150A	143	158	1.0	128	1.0	1.9	207	0.108
P4KE160	144	176	1.0	130	1.0	1.7	230	0.108
P4KE160A	152	168	1.0	136	1.0	1.8	219	0.108
P4KE170	153	187	1.0	138	1.0	1.6	244	0.108
P4KE170A	162	179	1.0	145	1.0	1.7	234	0.108
P4KE180	162	198	1.0	146	1.0	1.6	258	0.108
P4KE180A	171	189	1.0	154	1.0	1.6	246	0.108
P4KE200	180	220	1.0	162	1.0	1.4	287	0.108
P4KE200A	190	210	1.0	171	1.0	1.5	274	0.108
P4KE220	198	242	1.0	175	1.0	1.2	344	0.108
P4KE220A	209	231	1.0	185	1.0	1.2	328	0.108
P4KE250	225	275	1.0	202	1.0	1.1	360	0.110
P4KE250A	237	263	1.0	214	1.0	1.2	344	0.110
P4KE300	270	330	1.0	243	1.0	0.93	430	0.110
P4KE300A	285	315	1.0	256	1.0	1.0	414	0.110
P4KE350	315	385	1.0	284	1.0	0.79	504	0.110
P4KE350A	333	368	1.0	300	1.0	0.83	482	0.110
P4KE400	360	440	1.0	324	1.0	0.70	574	0.110
P4KE400A	380	420	1.0	342	1.0	0.73	548	0.110
P4KE440	396	484	1.0	356	1.0	0.63	631	0.110
P4KE440A	418	462	1.0	376	1.0	0.66	602	0.110
P4KE480	432	528	1.0	389	1.0	0.58	686	0.110
P4KE480A	456	504	1.0	408	1.0	0.61	658	0.110
P4KE510	459	561	1.0	413	1.0	0.55	729	0.110
P4KE510A	485	535	1.0	434	1.0	0.57	698	0.110
P4KE540	486	594	1.0	437	1.0	0.52	772	0.110
P4KE540A	513	567	1.0	459	1.0	0.54	740	0.110

Notes:

- (1) Pulse test: $t_p \leq 50ms$
- (2) Surge current waveform per Fig. 3 and derated per Fig. 2
- (3) For bidirectional types having V_{WM} of 10 volts and less, the I_D limit is doubled
- (4) All terms and symbols are consistent with ANSI/IEEE C62.35

Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 – Peak Pulse Power Rating Curve

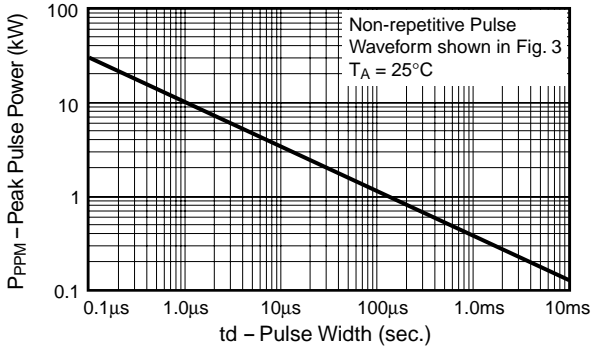


Fig. 2 – Pulse Derating Curve

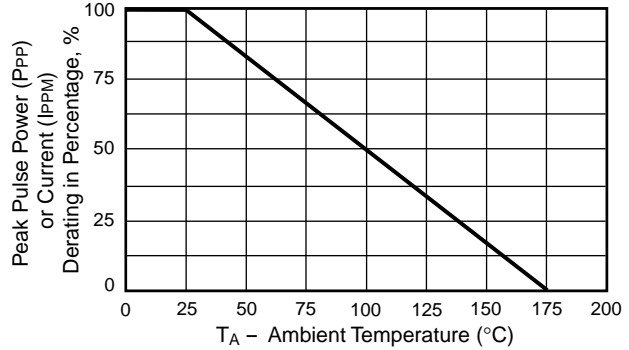


Fig. 3 – Pulse Waveform

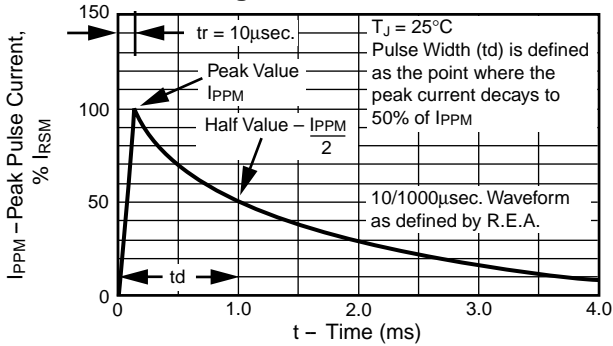


Fig. 4 – Typ. Junction Capacitance Uni-Directional

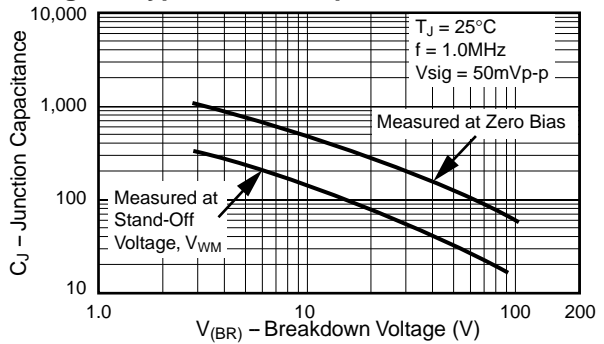


Fig. 5 – Steady State Power Derating Curve

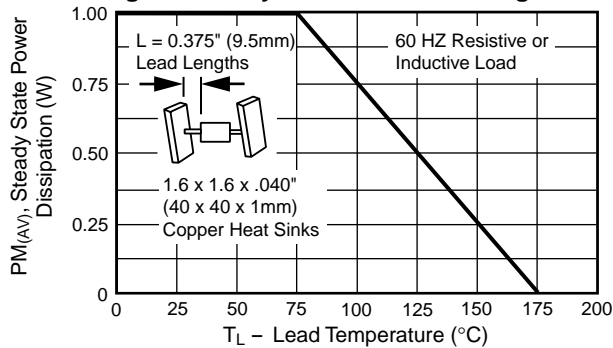


Fig. 6 - Max. Non-Repetitive Forward Surge Current Uni-Directional Only

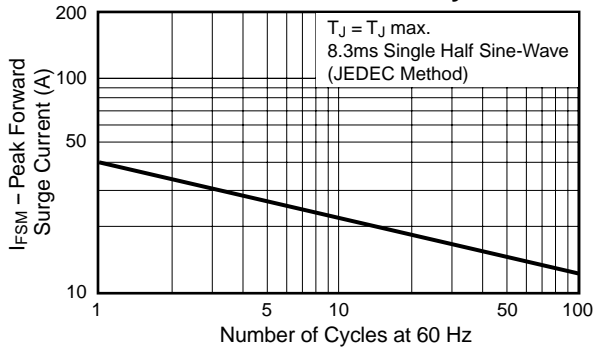


Fig. 7 – Typical Reverse Leakage Characteristics

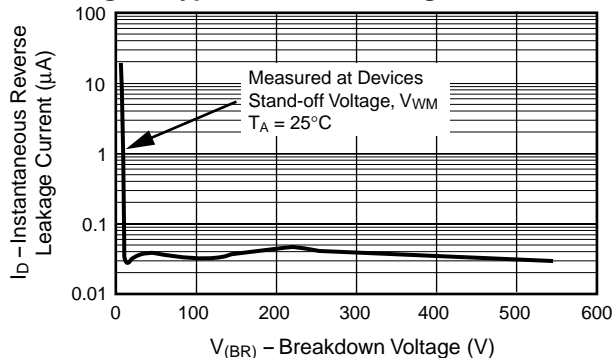
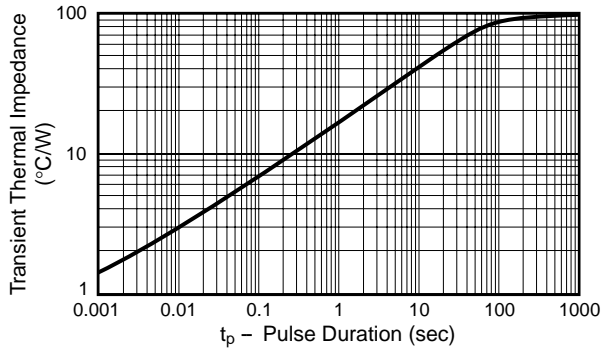


Fig. 8 – Typ. Transient Thermal Impedance





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